Silicon Carbide Schottky Diode

650 V, 12 A

Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 72 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery

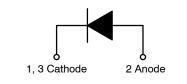
Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



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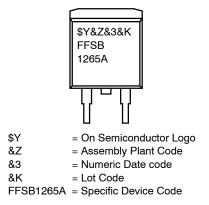
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D²PAK-3 (TO-263, 3-LEAD) CASE 418AJ

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSB1265A

ABSOLUTE MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit	
V _{RRM}	Peak Repetitive Reverse Voltage	650	V	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	Single Pulse Avalanche Energy (Note 1)		
١ _F	Continuous Rectified Forward Current @ $T_C < 143^{\circ}C$		12	А
	Continuous Rectified Forward Current @ T_C < 1	ontinuous Rectified Forward Current @ T_C < 135°C		А
I _{F, Max}	Non-Repetitive Peak Forward Surge Current	T _C = 25°C, 10 μs	940	А
		T _C = 150°C, 10 μs	890	А
I _{F, SM}	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	70	А
I _{F, RM}	Repetitive Forward Surge Current	Half-Sine Pulse, t _p = 8.3 ms	43	А
P _{tot}	Power Dissipation	$T_{C} = 25^{\circ}C$	100	W
		T _C = 150°C	17	W
T _J , T _{STG}	Operating and Storage Temperature Range	–55 to +175	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max	1.5	°C/W

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Packing Method	Reel Size	Tape Width	Shipping [†]
FFSB1265A	FFSB1265A	D ² -PAK	Tape and Reel	330 mm	24 mm	800 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ON WAFER (T_C = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V _F	Forward Voltage	I _F = 12 A, T _C = 25°C	-	1.50	1.75	V
		I _F = 12 A, T _C = 125°C	-	1.60	2.0	
		I _F = 12 A, T _C = 175°C	-	1.72	2.4	
I _R	Reverse Current	$V_{R} = 650 \text{ V}, \text{ T}_{C} = 25^{\circ}\text{C}$	-	-	200	μΑ
		$V_{\rm R}$ = 650 V, $T_{\rm C}$ = 125°C	-	-	400	
		$V_{R} = 650 \text{ V}, \text{ T}_{C} = 175^{\circ}\text{C}$	-	-	600	
Q _c	Total Capacitive Charge	V = 400 V	-	40	-	nC
С	Total Capacitance	V _R = 1 V, f = 100 kHz	-	665	-	pF
		V _R = 200 V, f = 100 kHz	-	74	-	1
		V _R = 400 V, f = 100 kHz	-	54	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. NOTES:

1. E_{AS} of 72 mJ is based on starting T_J = 25°C, L = 0.5 mH, I_{AS} = 17 A, V = 50 V.

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TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted)

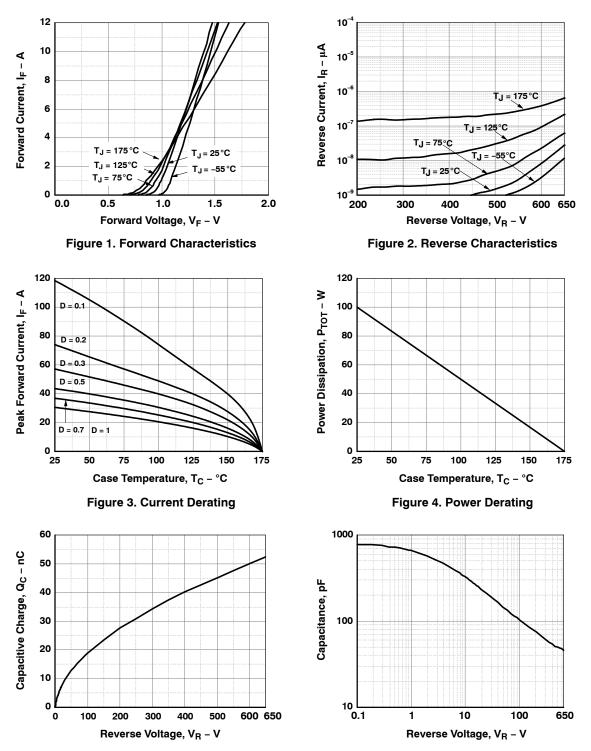


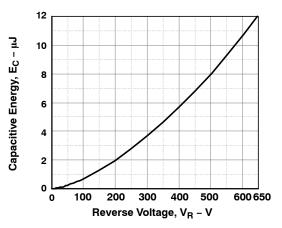
Figure 5. Capacitive Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage

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TYPICAL CHARACTERISTICS

(T_J = 25°C unless otherwise noted)





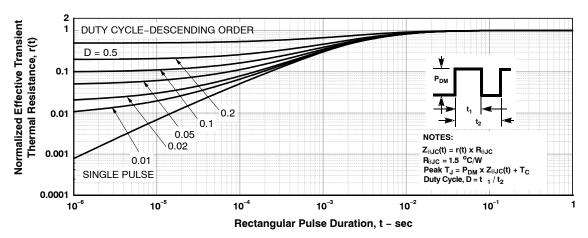
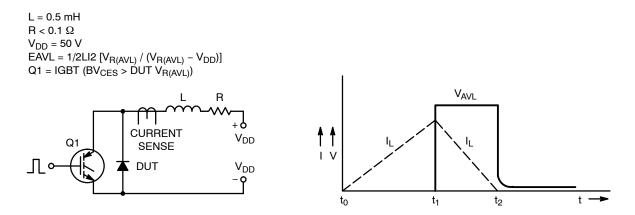
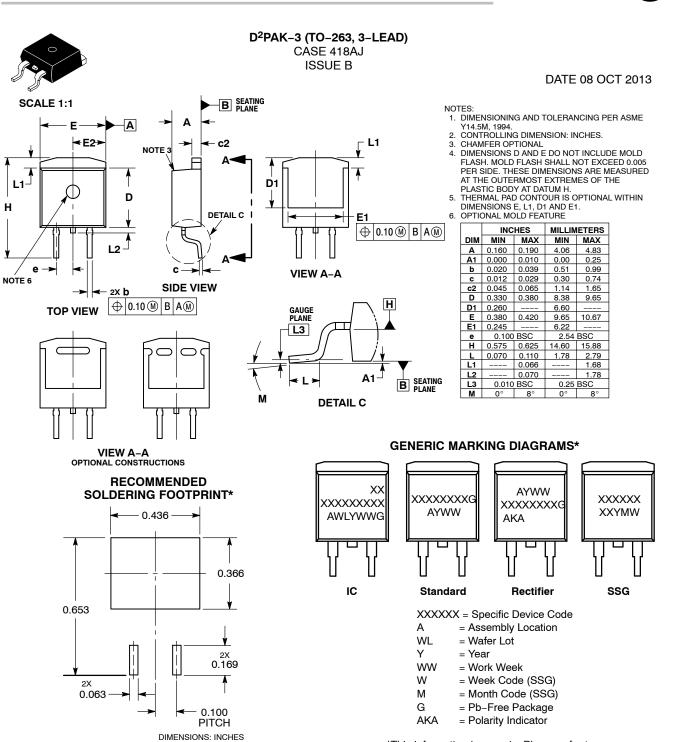


Figure 8. Junction-to-Case Transient Thermal Response Curve

TEST CIRCUIT AND WAVEFORMS







*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

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A	CORRECTED PITCH ON SOLDER FOOTPRINT TO BE FROM CENTER LINE TO LEAD. REQ. BY D. TRUHITTE.	25 JUL 2011			
В	ADDED GENERIC MARKING DIAGRAM FOR SSG. REQ. BY I. CAMBALIZA.	08 OCT 2013			

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